NSN 5962-01-162-7584

Memory Microcircuit - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5962-01-162-7584

Body Length: 1.260 inches **Body Width:** Between 0.350 inches and 0.390 inches **Body Height:** 0.210 inches **Maximum Power Dissipation Rating:** 935.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+165.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and schottky and 3-state output and w/enable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Transistor-transistor logic **Input Circuit Pattern:** 16 input **Case Outline Source And Designator:** D-7 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 5.5 volts power source **Time Rating Per Chacteristic:** 60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level output Memory Device Type: Ram **Test Data Document:** 81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

22 printed circuit

Specification Data:

81349-mil-m-38510/231 government specification

Shelf Life:

N/a

Unit Of Measure:

NSN 5962-01-162-7584

Memory Microcircuit - Page 2 of 2

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

